

Multiscale modelling of phonon transport

Verena Fritz

Olga Natalia Bedoya-Martinez

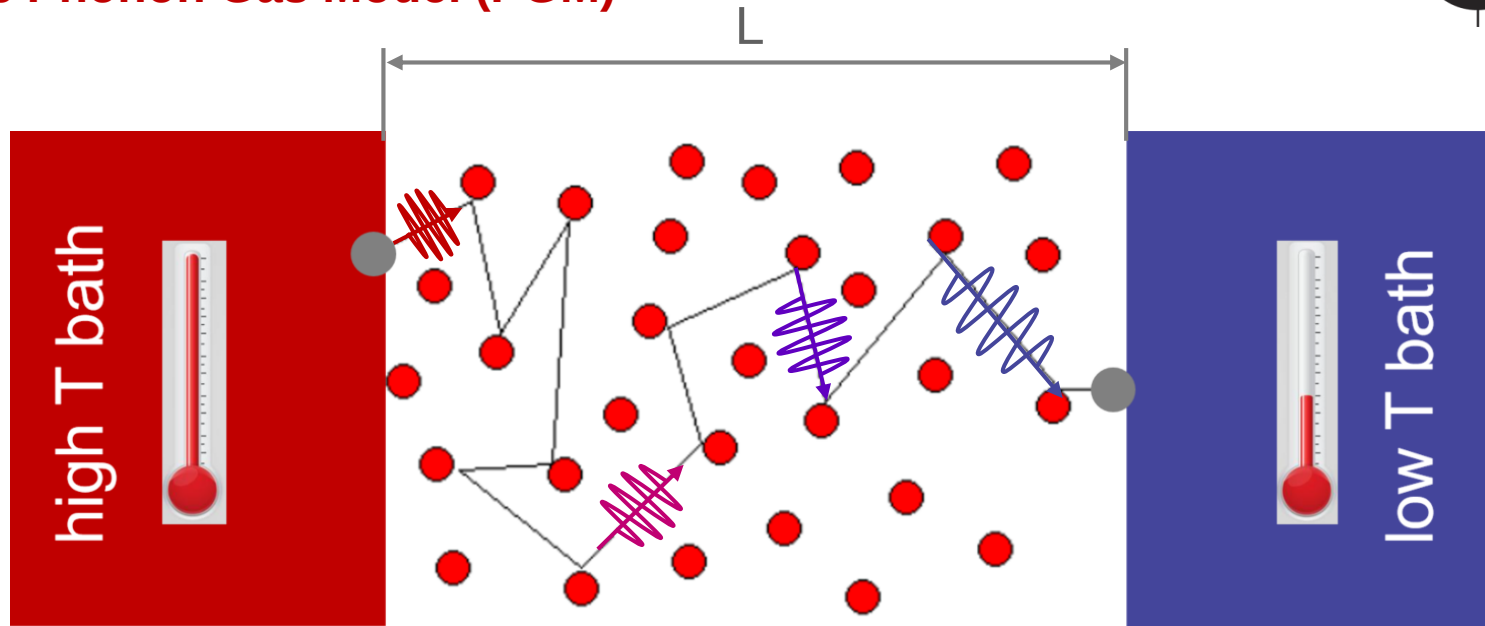
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Tagung des AK-Thermophysik, 08. – 09. April 2018, Leoben

The Phonon Gas Model (PGM)



$$C = \hbar \omega D \frac{\partial f}{\partial T} \quad \vec{v} = \frac{\partial \omega}{\partial \vec{k}} \quad \Lambda = \vec{v} \tau \quad \text{Kn} = \frac{\Lambda}{L}$$

THERMAL CONDUCTIVITY:

$$\kappa_v(\vec{k}) = C_v(\vec{k}) v_v(\vec{k}) \Lambda_v(\vec{k})$$

isotropic: $\omega(\vec{k}) = \omega(|\vec{k}|)$

$$\kappa_v(\omega) = C_v(\omega) v_v(\omega) \Lambda_v(\omega)$$

$$\kappa = \sum_v \int d\omega \kappa_v(\omega)$$

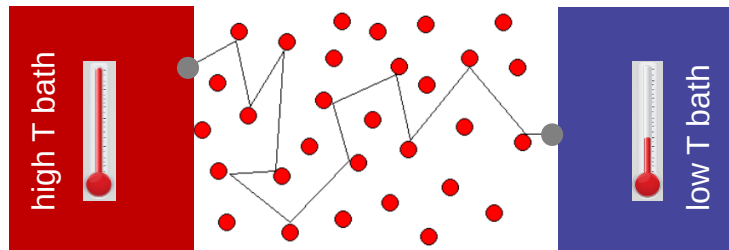
MOTIVATION: Multiscale modelling of phonon transport



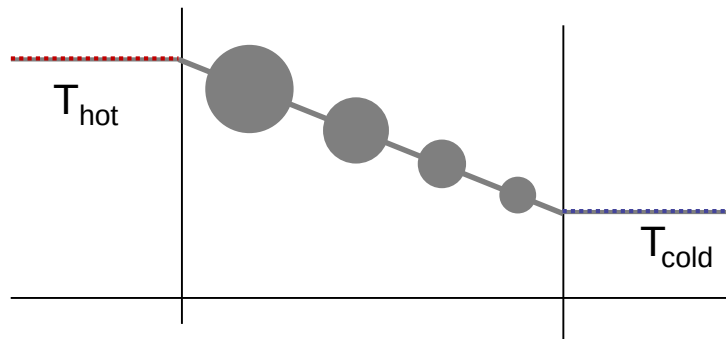
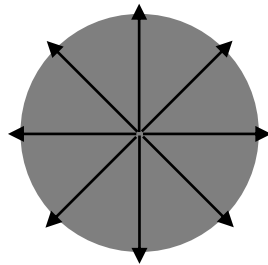
Diffusive vs ballistic transport → Breakdown of Fourier's law

Diffusive transport

$$Kn \ll 1$$

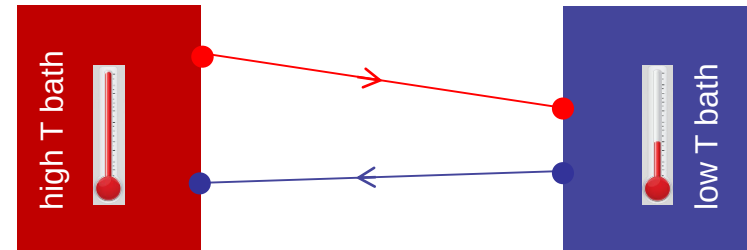


Isotropic “phonon radiation”
and contribution to temperature

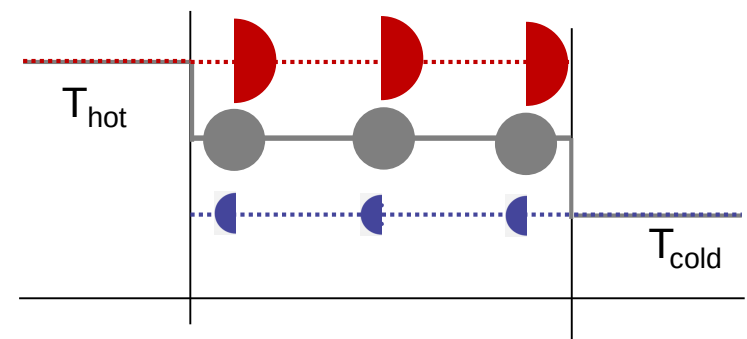
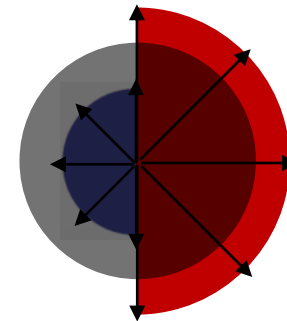


Ballistic transport

$$Kn \gg 1$$



Directional “phonon radiation”
and effective temperature



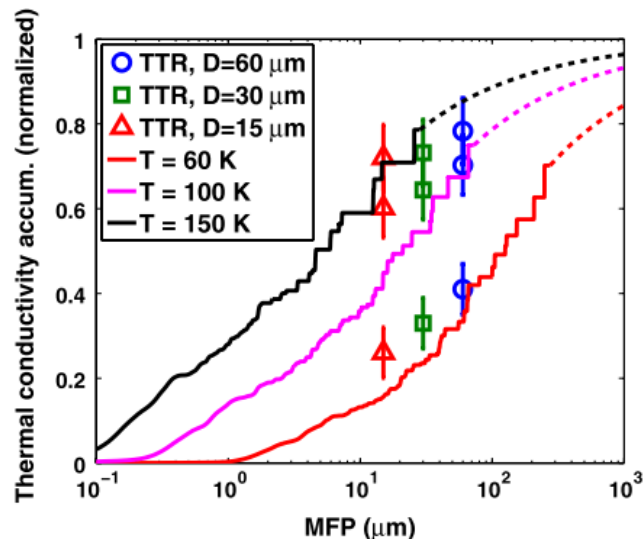


Thermal Conductivity Spectroscopy Technique to Measure Phonon Mean Free Paths

A. J. Minnich,¹ J. A. Johnson,² A. J. Schmidt,³ K. Esfarjani,¹ M. S. Dresselhaus,⁴ K. A. Nelson,² and G. Chen^{1,*}

...”Our approximation is that the ballistic group does not contribute to thermal transport due to the effectively infinite ballistic resistance; the thermal conductivity measured in the experiment is only due to the diffusive group...”

$$k_{\text{accum}}(\Lambda^*) = \int_0^{\Lambda^*} k_{\Lambda} d\Lambda = \int_0^{\Lambda^*} \frac{1}{3} C_{\Lambda}(\Lambda) v(\Lambda) \Lambda d\Lambda.$$



→ simplified assumption:
 phonons only contribute up to
 a certain cutoff MFP Λ^* :

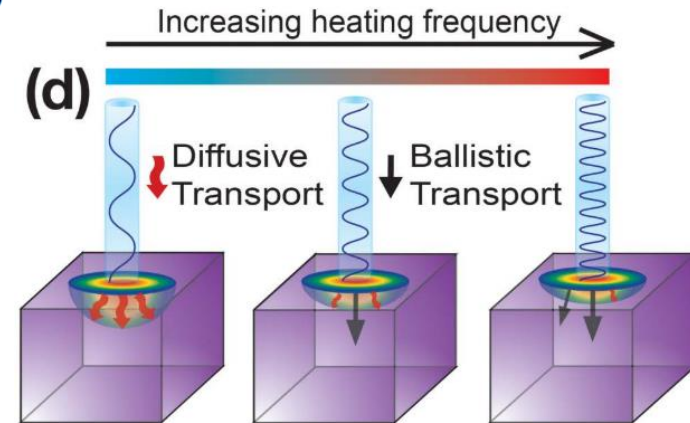
MOTIVATION: TDTR → MFP spectra (via modulation frequency)



SCIENTIFIC REPORTS | 3 : 2963 | DOI: 10.1038/srep02963

Universal phonon mean free path spectra in crystalline semiconductors at high temperature

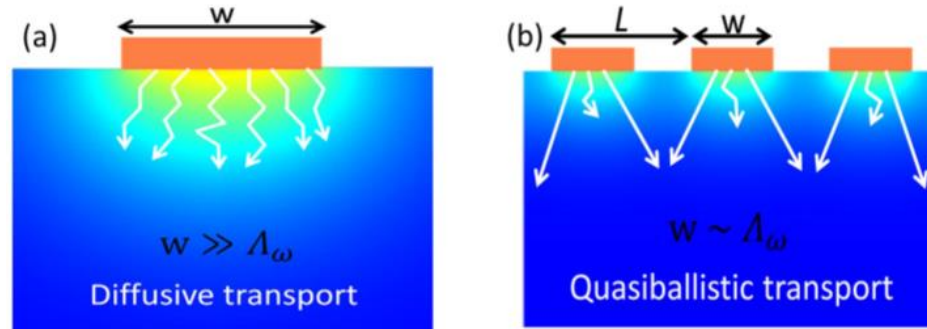
Justin P. Freedman¹, Jacob H. Leach², Edward A. Preble², Zlatko Sitar³, Robert F. Davis¹
& Jonathan A. Malen^{1,4}



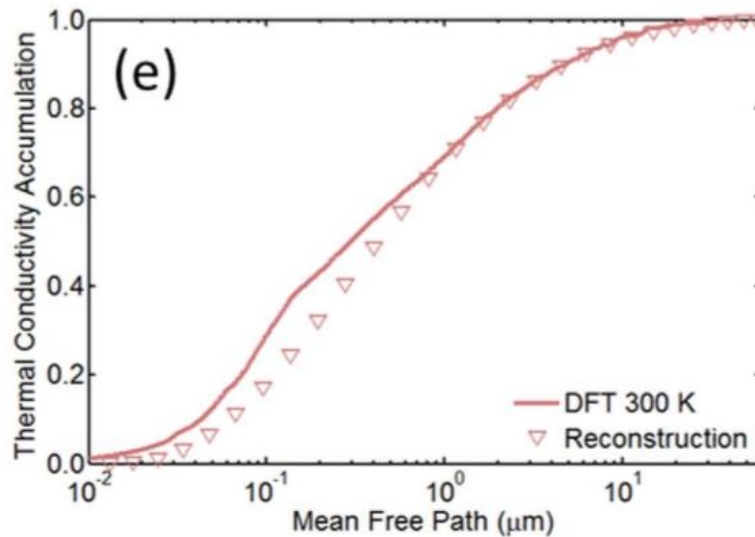
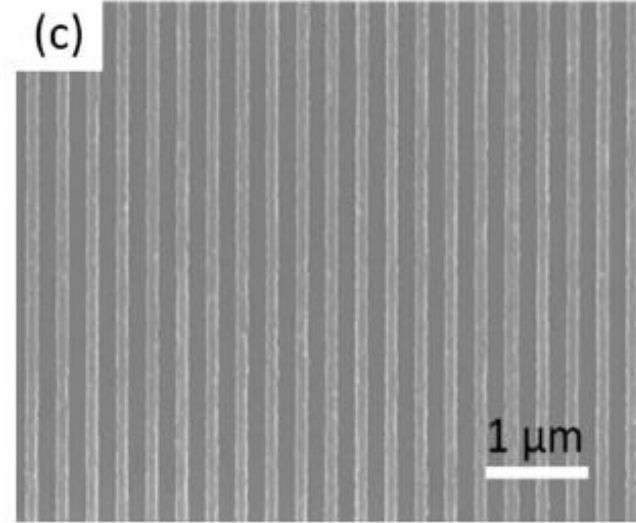
50% of thermal conductivity accumulation @ RT:

- GaN $1.0 \pm 0.2 \mu\text{m}$
- AlN $2.5 \pm 0.8 \mu\text{m}$
- SiC $4.2 \pm 0.9 \mu\text{m}$

MOTIVATION: TDTR → MFP spectra (via heater structures)



Al grating on Si substrate



Zeng, Lingping, et al. "Measuring phonon mean free path distributions by probing quasiballistic phonon transport in grating nanostructures." *Scientific reports* 5 (2015): 17131.

$$k_{eff}(w) = \int_0^\infty S(\eta) f(\Lambda) d\Lambda \quad \eta = \frac{\Lambda}{w}$$

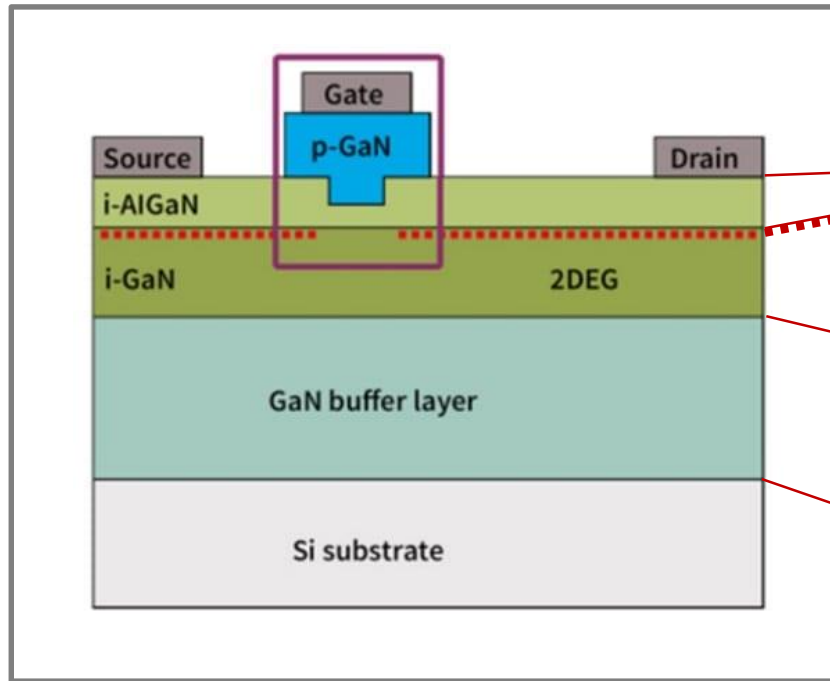
Using suppression fuction $S(\eta)$ (derived from BTE) and lengthscale dependent thermal conductivity measured on for different metal linewidths $k_{eff}(w)$

→ Cumulative phonon MFP distribution: $F(\Lambda) = \int_0^\Lambda f(\Lambda') d\Lambda'$

MOTIVATION: Application

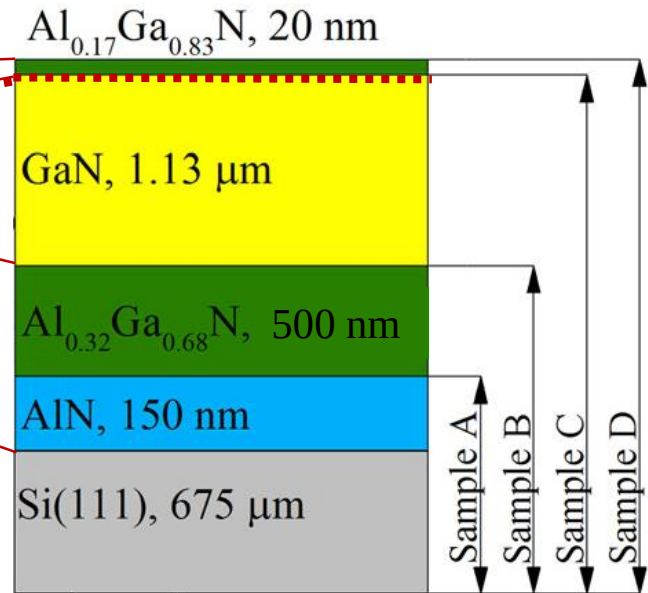


E.g. Infineon “CoolGaN” device schematics:



Reisinger et al., Appl. Phys. Lett. 111,162103 (2017)

Example layer stack:



50% of thermal conductivity accumulation @ RT [DOI: 10.1038/srep02963]:

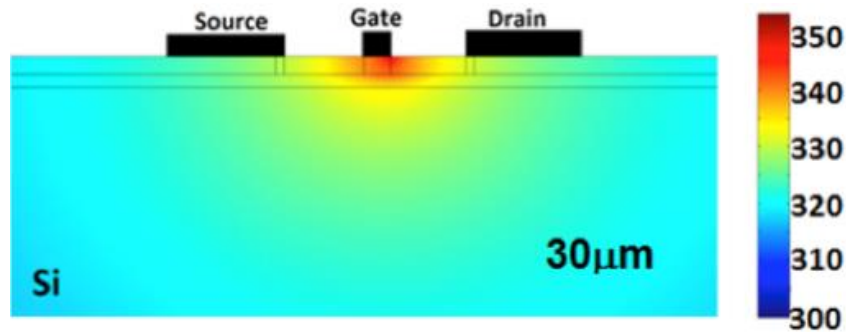
- GaN $1.0 \pm 0.2 \mu\text{m}$
- AlN $2.5 \pm 0.8 \mu\text{m}$

Compare Si 0.5 μm, from Henry and Chen, J. Comp. Theo. Nanosci 5, 1 (2008)

MOTIVATION: Application



E.g. Infineon “CoolGaN” device schematics:



Normally Fourier type simulations are used
(they are very wrong)

J. Heat Transfer 139(10), 102701

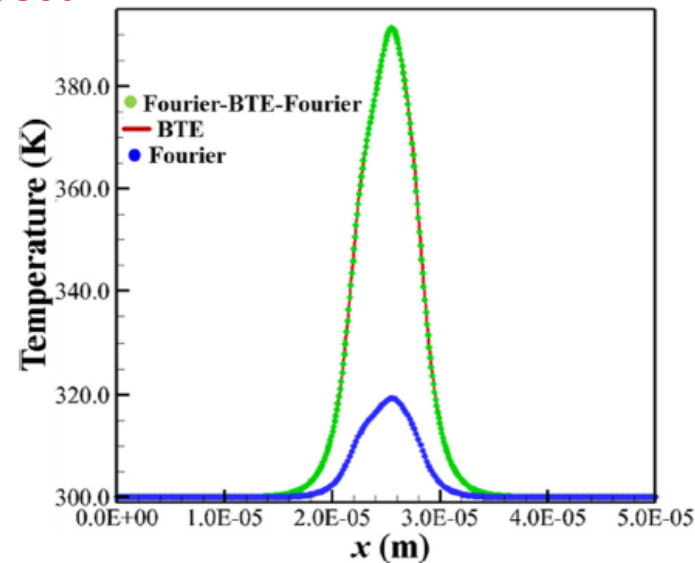


Fig. 4 Lattice temperature variation in the domain along the x -direction at the middle of the buffer (dotted line in the inset) at $y = 1.9 \times 10^{-6} \mu\text{m}$. The Fourier model significantly underpredicts the hot-spot temperature.

MOTIVATION: TDTR $\rightarrow$ interface phonon transmission (enabled by ab initio computations)

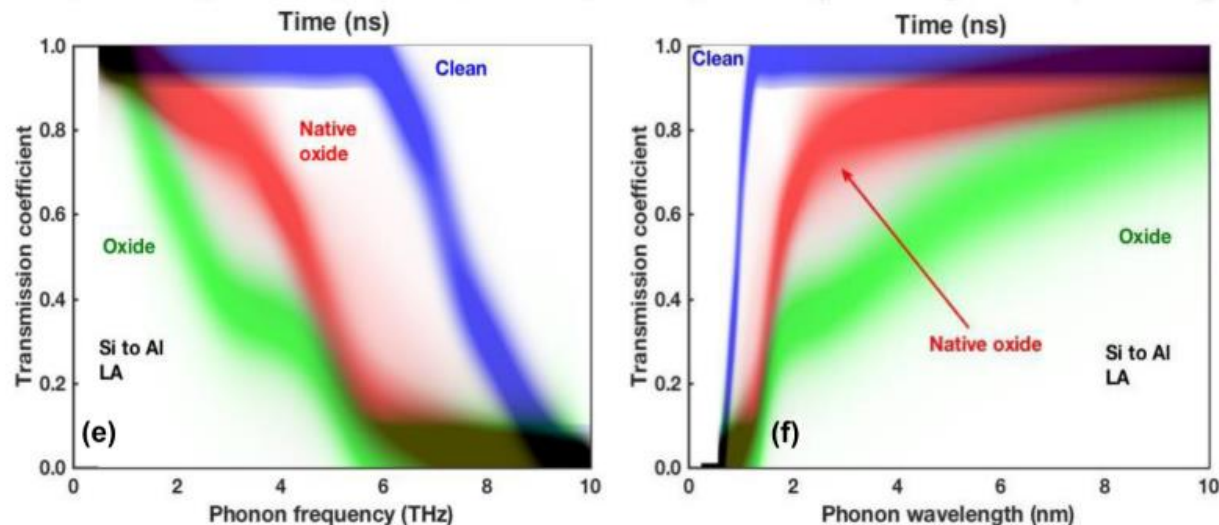
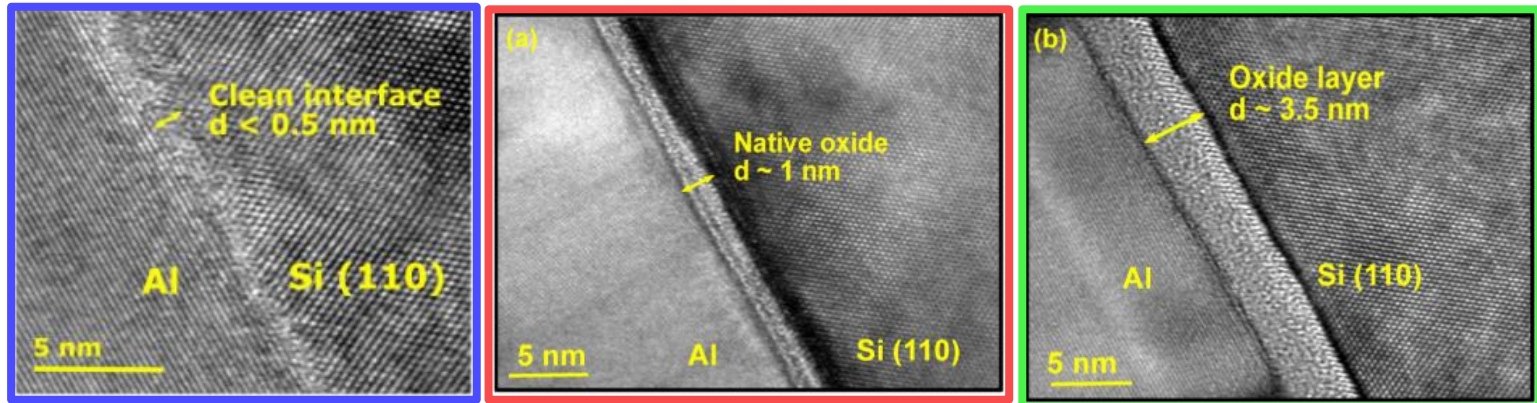


PHYSICAL REVIEW B **95**, 205423 (2017)



Experimental metrology to obtain thermal phonon transmission coefficients at solid interfaces

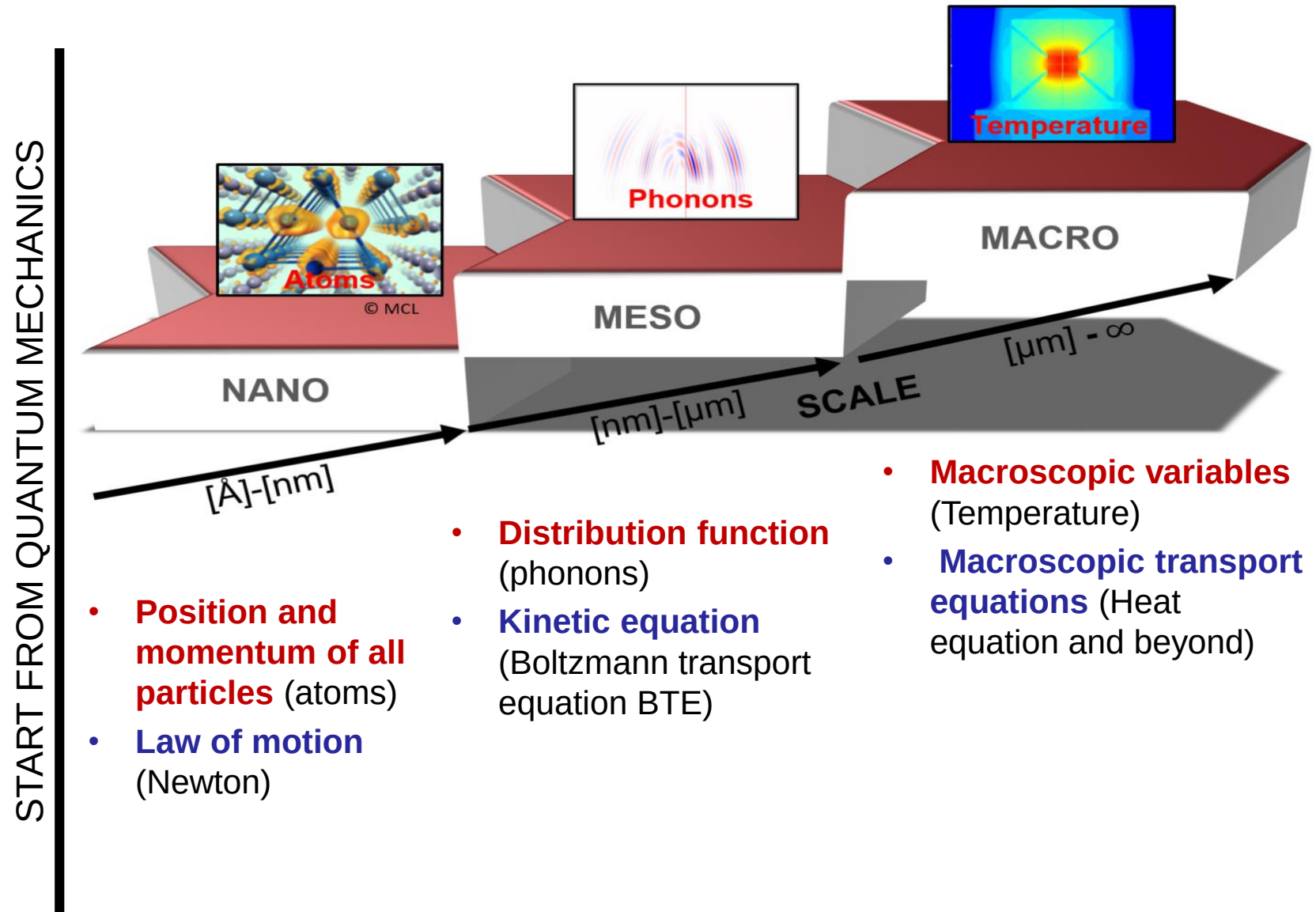
Chengyun Hua,¹ Xiangwen Chen,² Navaneetha K. Ravichandran,³ and Austin J. Minnich^{2,*}

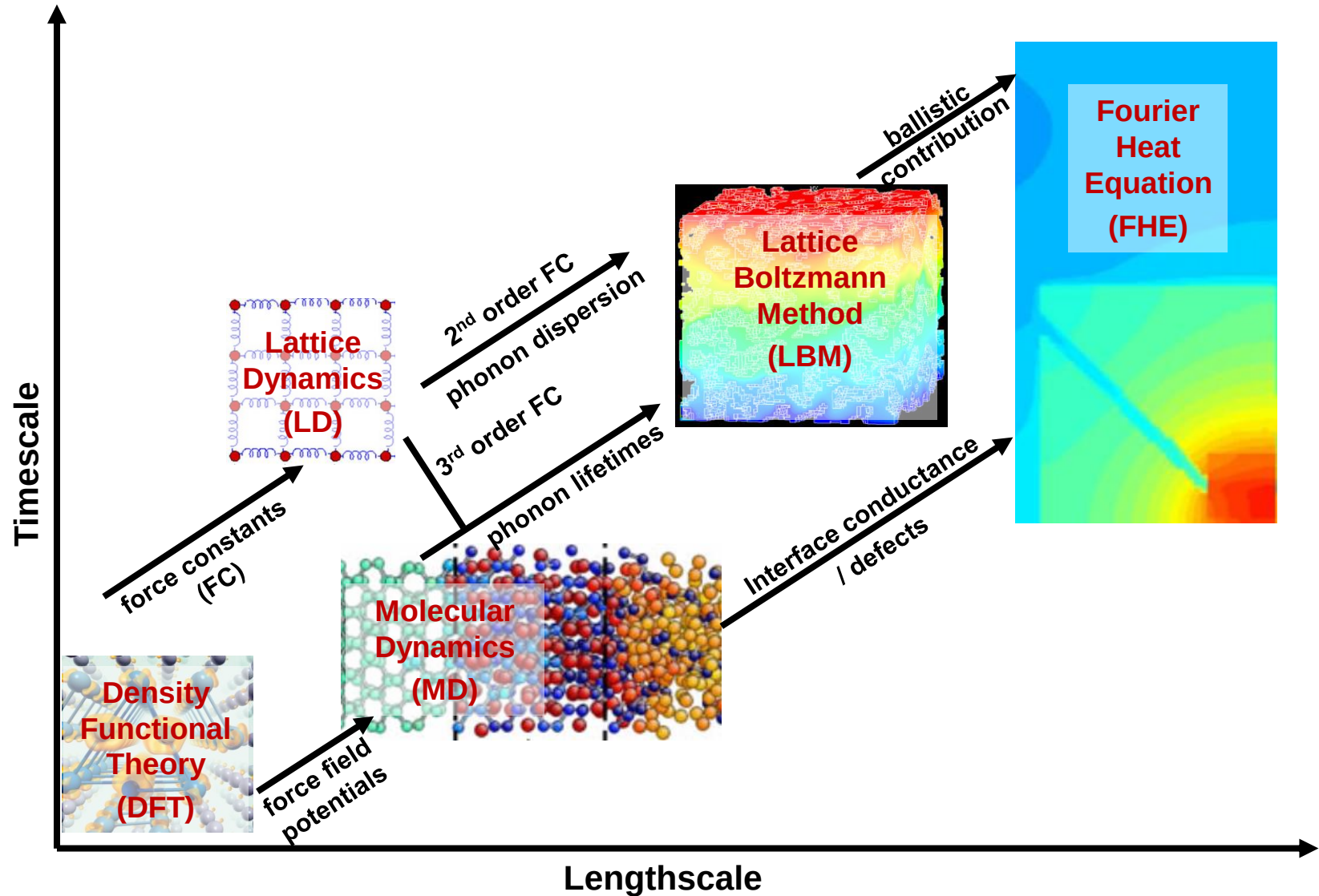


Multiscale modelling of phonon transport



→ **Different scales** → **different descriptions**

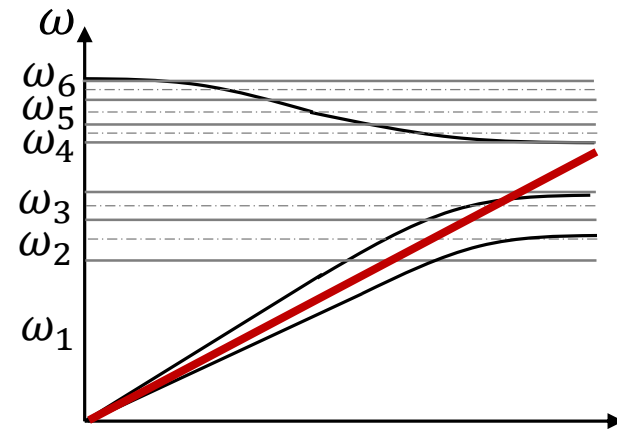
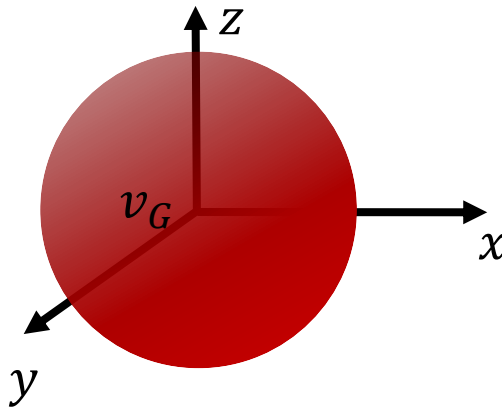


Methods

Lattice Boltzmann method (LBM)

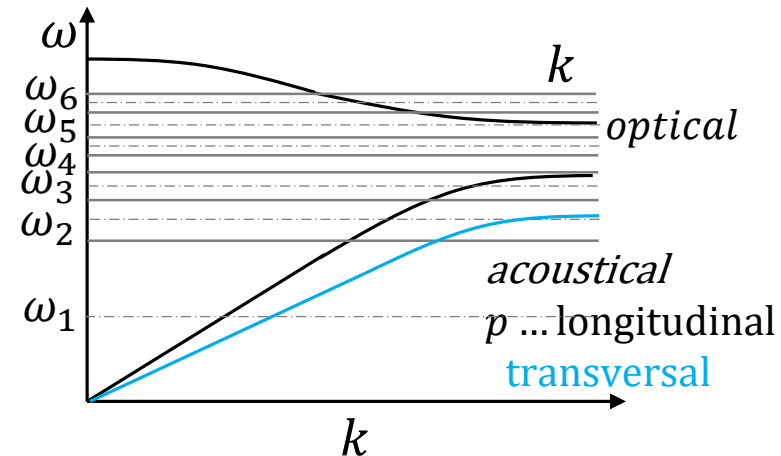
- Gray approximation**

All modes are represented by one representative isotropic constant group velocity v_G



- Beyond gray approximation → dispersion lattice Boltzmann**

Each **direction**, **energy region** and **polarization** has its own group velocity $v_i(\omega_j, p)$



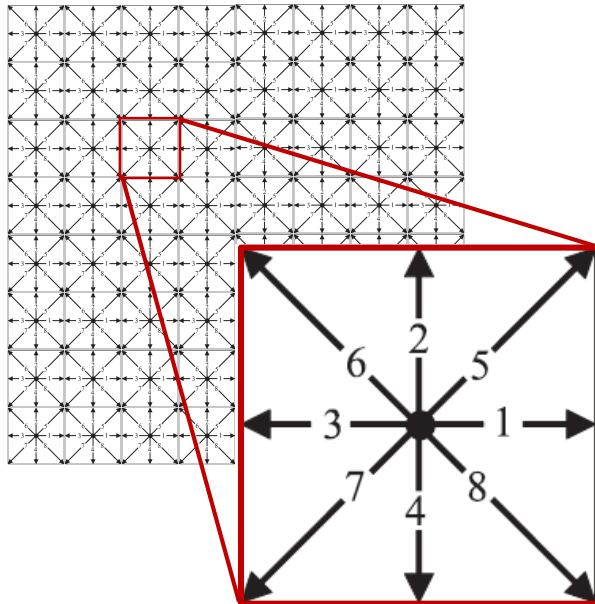
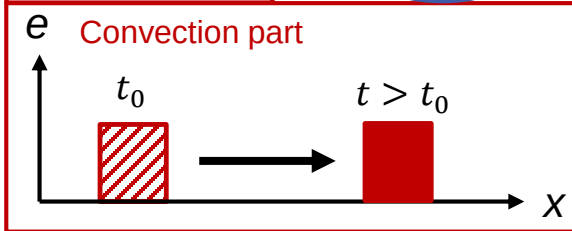
Escobar, Rodrigo A., and Cristina H. Amon. "Thin film phonon heat conduction by the dispersion lattice Boltzmann method." *Journal of Heat Transfer* 130.9 (2008)

Lattice Boltzmann method (LBM)

Boltzmann equation in energy formulation $e(T) = \sum_p \int f \hbar \omega_p D_p(\omega) d\omega$

$$\frac{\partial e}{\partial t} + \mathbf{v} \cdot \nabla e = - \frac{e - e^0}{\tau_r}$$

Scattering term
= driving force back to
equilibrium distribution



Discretize direction (i) wise → Lattice Boltzmann

$$\frac{e_i(x, t + \Delta t) - e_i(x, t)}{\Delta t} + c_i \frac{e_i(x + \Delta x, t + \Delta t) - e_i(x, t + \Delta t)}{\Delta x} = - \frac{e_i(x, t) - e_i^0(x, t)}{\tau_r}$$

Convection ("streaming")

Diffusion

$$e_1(x_i, y_j, t_{n+1}) = (1 - W)e_1(x_{i+1}, y_j, t_n) + We^0(x_{i+1}, y_j, t_n)$$

$$e_2(x_i, y_j, t_{n+1}) = (1 - W)e_2(x_i, y_{j+1}, t_n) + We^0(x_i, y_{j+1}, t_n)$$

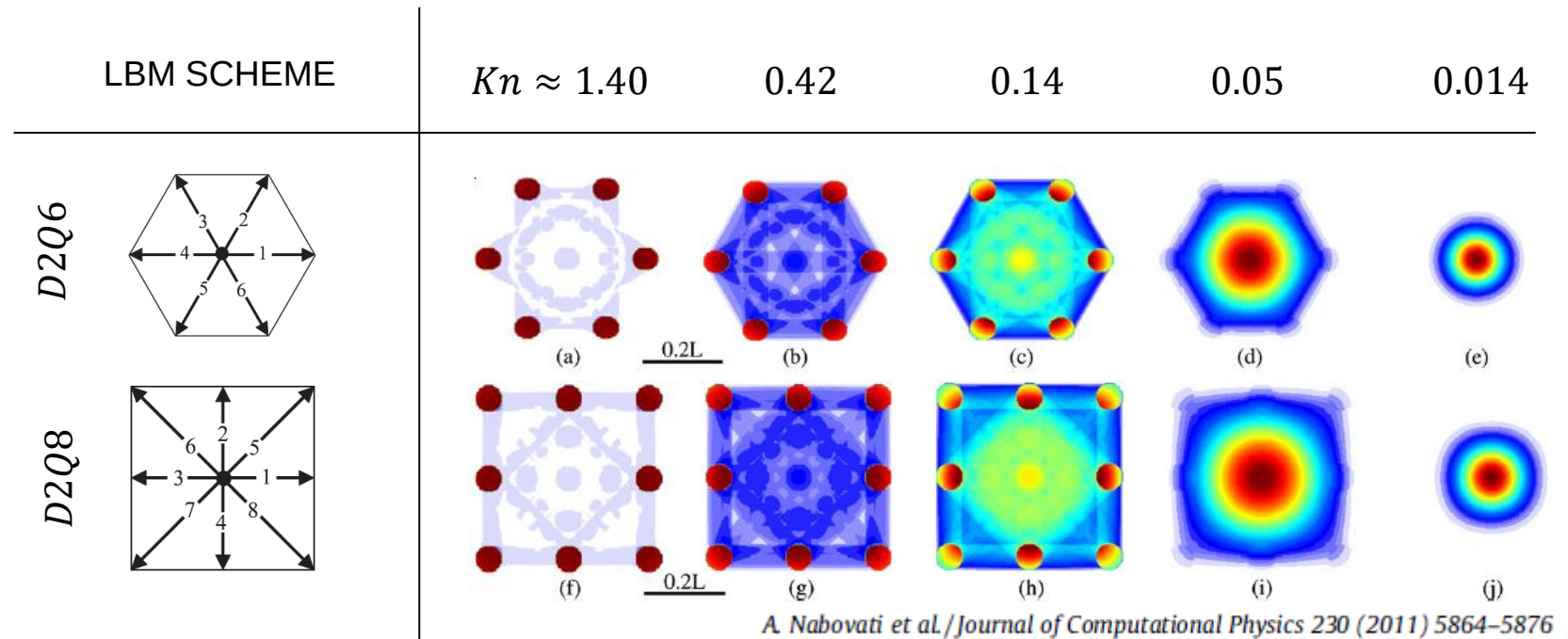
$$e_3(x_i, y_j, t_{n+1}) = (1 - W)e_3(x_{i-1}, y_j, t_n) + We^0(x_{i-1}, y_j, t_n)$$

$$e_8(x_i, y_j, t_{n+1}) = (1 - W)e_8(x_{i+1}, y_{j+1}, t_n) + We^0(x_{i+1}, y_{j+1}, t_n)$$

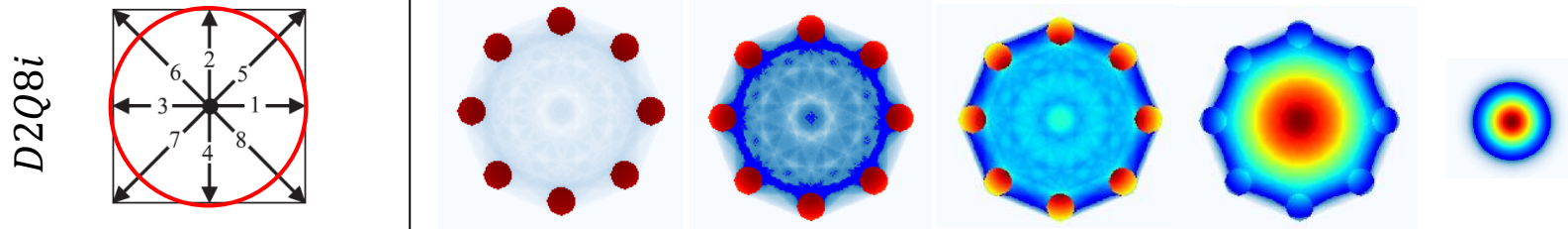
$$e^0(x_i, y_j, t_n) = \sum_{Q=1}^8 \frac{e_Q}{8}$$

Escobar, Rodrigo A. *et al.*, International Journal of Heat and Mass Transfer 49 (2006).

LBM, (an)isotropy for high Knudsen numbers



our time adaptive scheme

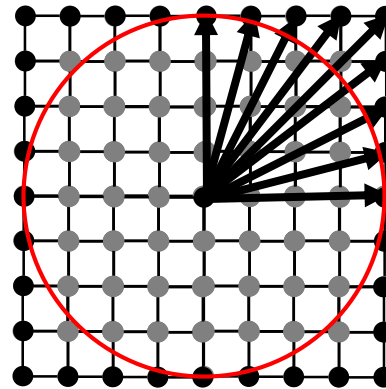


...in preparation

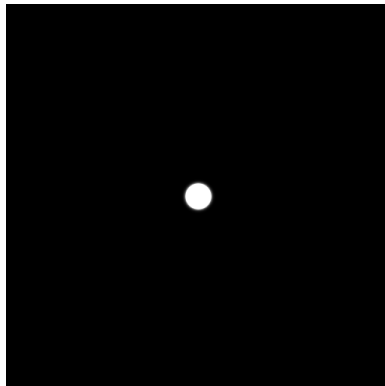
Extending LBM to phonon transport towards the ballistic regime

- use lattice points further appart for more lattice directions

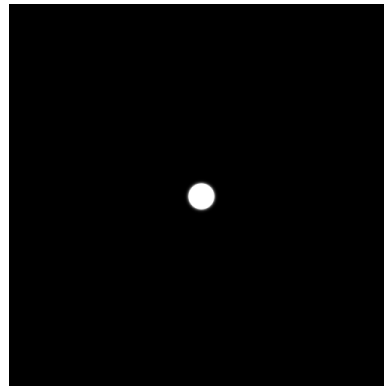
D2Q32i



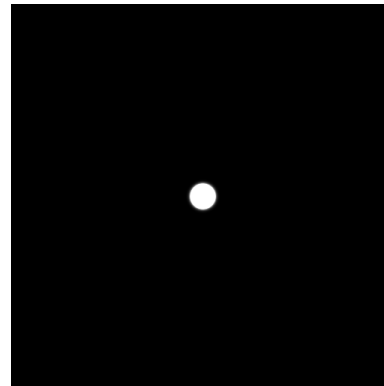
D2Q8i



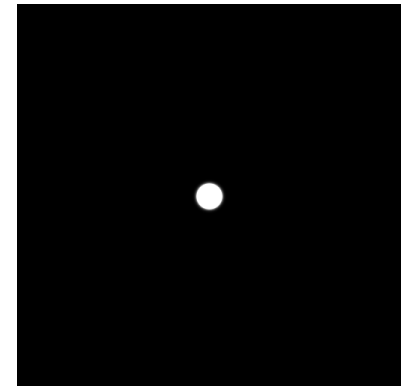
D2Q16i

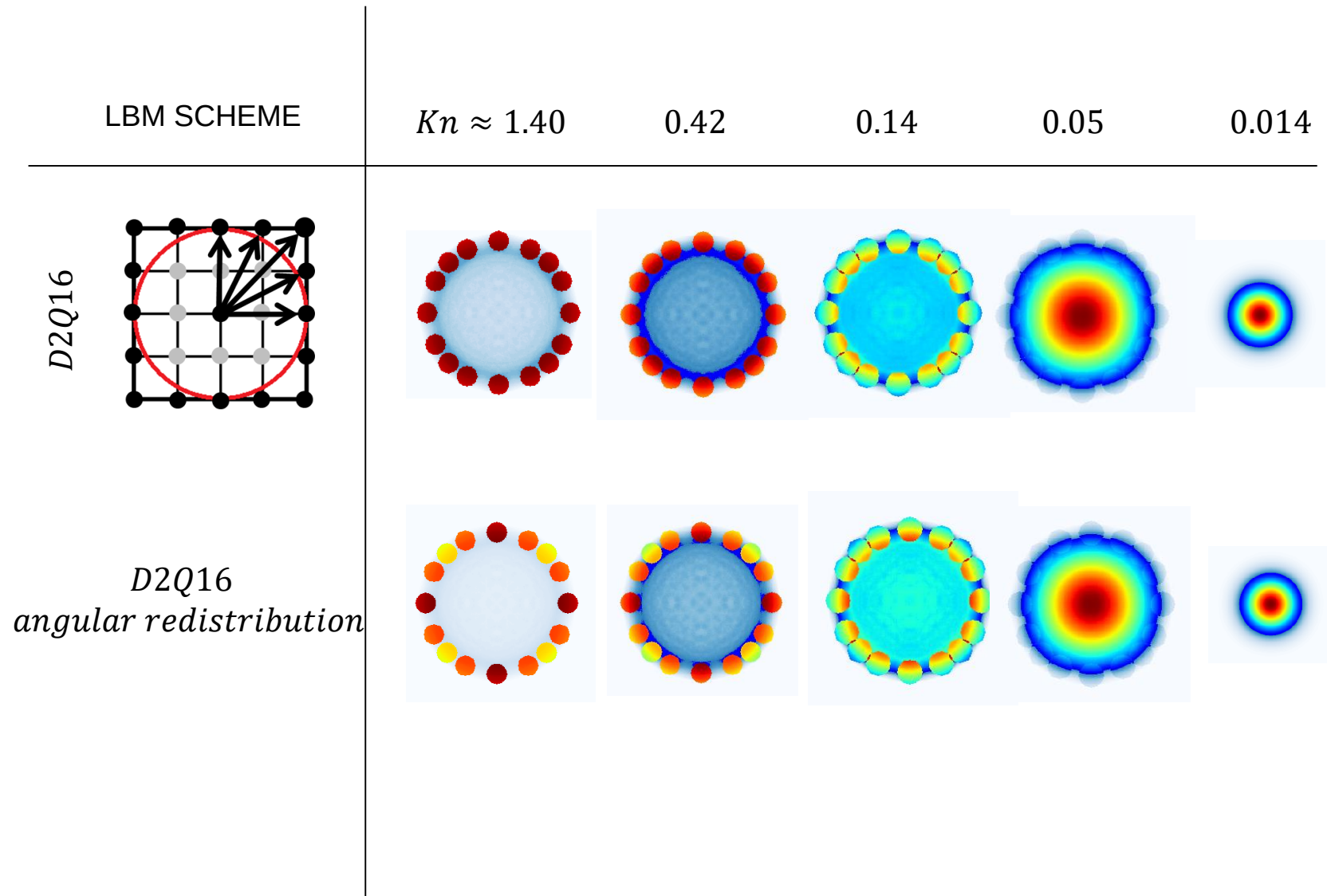


D2Q24i



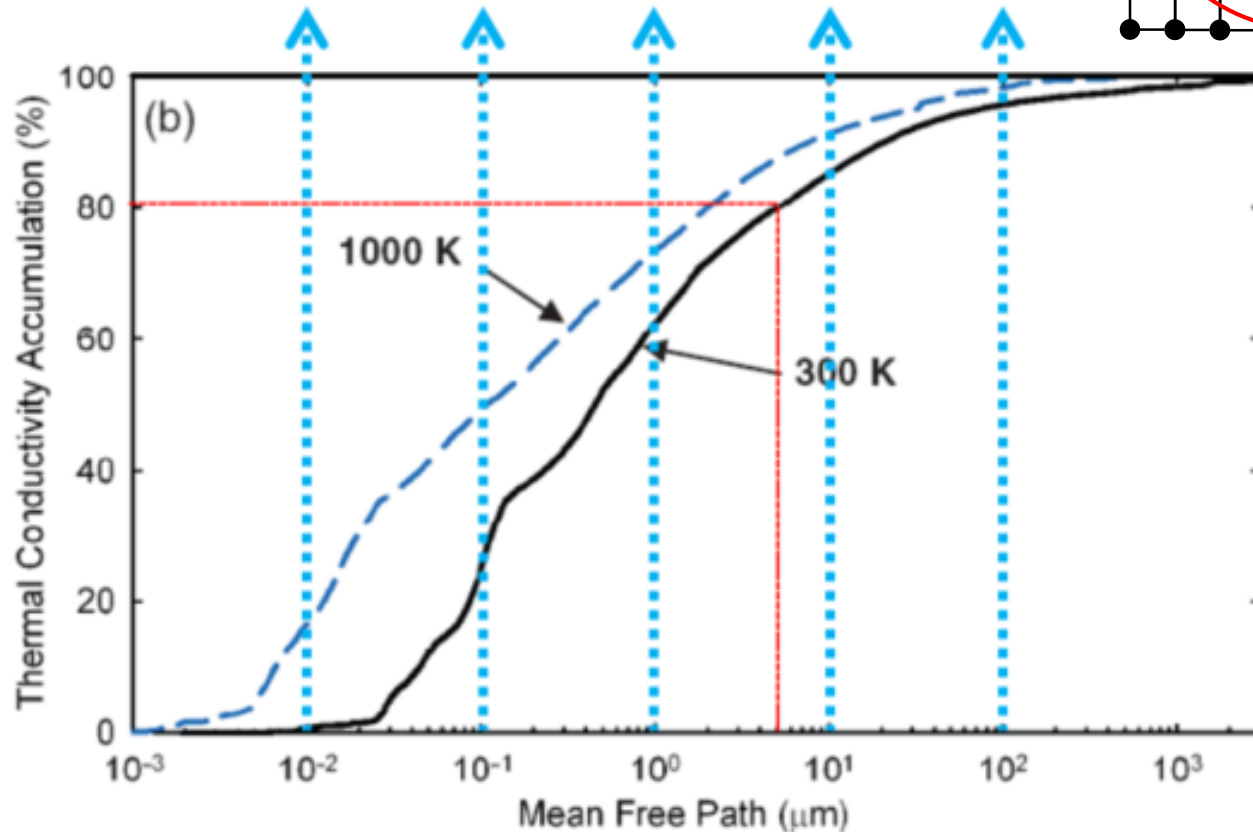
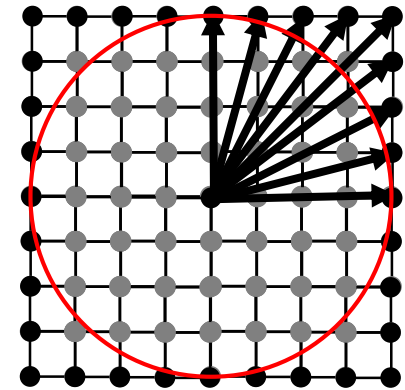
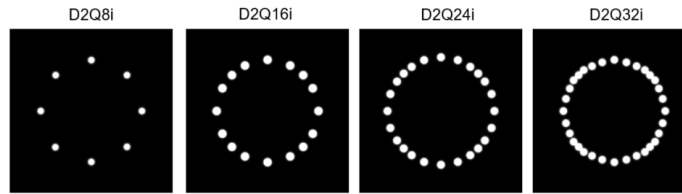
D2Q32i

 $Kn = \infty$



Extending LBM to phonon transport towards the ballistic regime

adaptive number of directional discretizations



New paradigm: The Green Kubo Modal Analysis (GKMA)

Modal contribution to thermal conductivity

$$\kappa(n) = \frac{V}{k_B T^2} \int_0^\infty \langle \mathbf{Q}(n, t) \cdot \mathbf{Q}(0) \rangle dt$$

Heat current in real space coordinates (from MD runs)

$$\mathbf{Q}(t) = \sum_n \frac{1}{V} \sum_i \left[E_i \dot{\mathbf{x}}_i(n, t) + \sum_j (-\nabla_{\mathbf{r}_i} \Phi_j \cdot \dot{\mathbf{x}}_i(n, t)) \mathbf{r}_{ij} \right]$$

Real space coordinates expressed in normal modes

$$\dot{\mathbf{x}}_j(t) = \sum_n \dot{\mathbf{x}}_j(n, t) = \frac{1}{m_j^{1/2}} \sum_n \mathbf{p}_j(n) \dot{X}(n, t)$$

(N atoms vibrating about their equilibrium sites $\rightarrow$ 3N normal modes)GKMA = modal decomposition of heat current $\rightarrow$ mode-mode correlation

PGM = requires well defined phonon properties



W Lv and A Henry
New J. Phys. 18 (2016) 013028

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THANK YOU

MCL THERMAL TRANSPORT PIRATES



Modelling

Experiments

DFT

MD

BTE

Fourier

TDTR

SThM



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Verena Fritz



Katrin Fladischer



Verena Leitgeb



Jürgen Spitaler



Natalia Bedoya



René Hammer



Lisa Mitterhuber



Stefan Defregger

THANK YOU



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